SSCHE4000 SSCHE6000 SSCHE10000 SSCHE11000 SSCHE15000 SSCHE20000



TECHNICAL DATA DATA SHEET 603, REV. -

HIGH VOLTAGE RECTIFIER STACKS

DESCRIPTION: A 4000/6000/8000/10000/11000/15000/20000 VOLT, 0.25 AMP, 70 NANOSECOND, HIGH VOLTAGE RECTIFIERS.

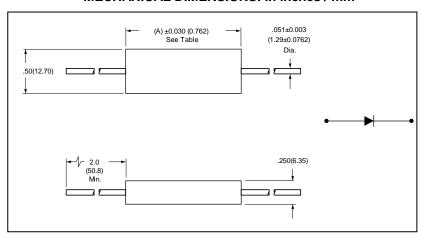
MAX RATINGS/ELECTRICAL CHARACTRISTIC ALL RATINGS ARE AT TA = 25 C) UNLESS OTHERWISE SPECIFIED

RATING	SYMBOL	MAX.	UNITS
PEAK INVERSE VOLTAGE (PER LEG)			
SSCHE4000	PIV	4000	Volts
SSCHE6000		6000	
SSCHE8000		8000	
SSCHE10000		10000	
SSCHE11000		11000	
SSCHE15000		15000	
SSCHE20000		20000	
MAXIMUM FORWARD VOLTAGE DROP (PER LEG) (I _f = 0.2 Amps)			
SSCHE4000	V_{f}	10	Volts
SSCHE6000		15	
SSCHE8000		20	
SSCHE10000		25	
SSCHE11000		30	
SSCHE15000		40	
SSCHE20000		50	
MAXIMUM AVERAGE DC OUTPUT CURRENT (T _C = 55 °C)	Io	0.25	Amps
When operating in oil, the output current capabilities are doubled.			
MAXIMUM AVERAGE DC OUTPUT CURRENT ($T_C = 100 ^{\circ}$ C)	I _O	0.13	Amps
PEAK SINGLE CYCLE SURGE CURRENT t_p = 8.3 msec.	I _{PK}	20	Amps
MAXIMUM REVERSE CURRENT @ PIV (T _A = 25°C)	I _{rr}	10	μА
MAXIMUM REVERSE CURRENT @ PIV (T _A = 100°C)	Im	100	μΑ
MAXIMUM REVERSE RECOVERY TIME ($I_f = 0.5A$, $I_r = 1.0A$, $I_{rr} = 0.25A$)	t _{rr}	70	nsec
MAXIMUM OPERATING AND STORAGE TEMPERATURE RANGE	T _{op, stg}	-55 to +150	°C

SENSITRON

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MECHANICAL DIMENSIONS: In Inches / mm



* Case Material: Molded Epoxy

FIG. 418

Table A

Type Number	Package Length
SSCHE4000	1.125
SSCHE6000	1.625
SSCHE8000	2.000
SSCHE10000	2.375
SSCHE11000	2.750
SSCHE15000	3.500
SSCHE20000	4.250

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